

# PEMD3

# 50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

28 December 2022

Product data sheet

## 1. General description

NPN/PNP Resistor-Equipped double Transistor (RET) in an ultra small and flat lead SOT666 Surface-Mounted Device (SMD) plastic package.

PNP/PNP complement: PEMB11 NPN/NPN complement: PEMH11

## 2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- · Reduces component count
- · Reduces pick and place costs

## 3. Applications

- Low current peripheral driver
- Controlling IC inputs
- · Replaces general-purpose transistors in digital applications

## 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor,	Per transistor, for the PNP transistor with negative polarity						
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	50	V
I <sub>O</sub>	output current			-	-	100	mA
R1	bias resistor 1 (input)		[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	

[1] See "Section 11: Test information" for resistor calculation and test conditions.



# 5. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	I1	input (base) TR1	6 5 4	
3	O2	output (collector) TR2		R1 R2
4	GND2	GND (emitter) TR2		TR2
5	12	input (base) TR2	0	TR1 R2 R1
6	01	output (collector) TR1	1 2 3	
			SOT666	CANDA 14 00
				GND1 I1 O2 006aaa143

# 6. Ordering information

**Table 3. Ordering information** 

Type number	Package		
	Name	Description	Version
PEMD3	SOT666	plastic, surface-mounted package; 6 leads; 0.5 mm pitch; 1.6 mm x 1.2 mm x 0.55 mm body	<u>SOT666</u>

## 7. Marking

#### Table 4. Marking codes

Type number	Marking code
PEMD3	D3

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$ 

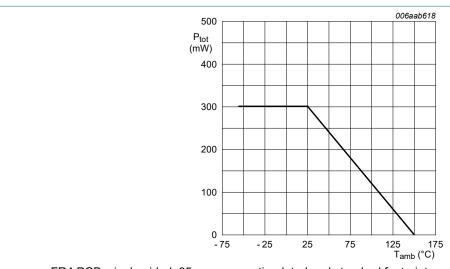
# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transiste	or, for the PNP transistor wit	n negative polarity				
V <sub>CBO</sub>	collector-base voltage	open emitter		-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	10	V
V <sub>I</sub>	input voltage	input voltage TR1		-	40	V
				-	-10	V
		input voltage TR2		-	10	V
				-	-40	V
Io	output current			-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	200	mW
Per device	<u> </u>		,			
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	300	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.



FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint

Fig. 1. Per device: Power derating curve

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$ 

## 9. Thermal characteristics

#### **Table 6. Thermal characteristics**

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	417	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.

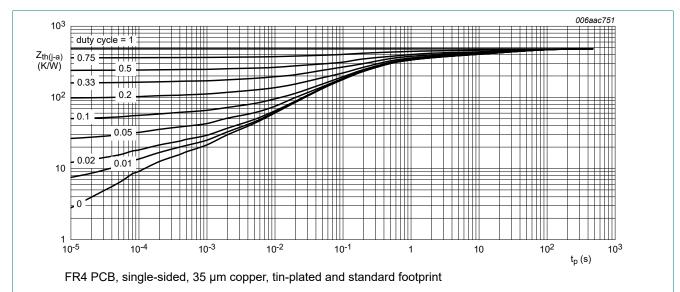


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$ 

## 10. Characteristics

#### **Table 7. Characteristics**

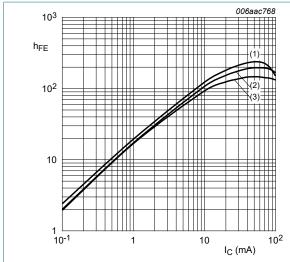
50 - 50 - - - - -	- 100 1 5 400	V V nA µA µA
50 -	1 5	V nA μA μA
-	1 5	nA μA μA
	1 5	μΑ
-	5	μΑ
-		
-	400	
		μA
30 -	-	
-	150	mV
1.	1 0.8	V
2.5 1.8	8 -	V
7 10	13	kΩ
).8 1	1.2	
	,	
-	2.5	pF
23	30 -	MHz
·	•	<u> </u>
-	3	pF
18	30 -	MHz
2	- 1. .5 1. .8 1	- 150  1.1 0.8  .5 1.8 - 10 13  .8 1 1.2  - 2.5  230 -

<sup>[1]</sup> See "Section 11: Test information" for resistor calculation and test conditions.

**Product data sheet** 

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<sup>[2]</sup> Characteristics of built-in transistor



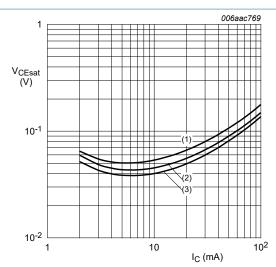
$$V_{CE} = 5 V$$

$$V_{CE} = 5 V$$
  
(1)  $T_{amb} = 100 ^{\circ}C$ 

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 ^{\circ}C$$
  
(3)  $T_{amb} = -40 ^{\circ}C$ 

TR1 (NPN): DC current gain as a function of Fig. 3. collector current; typical values

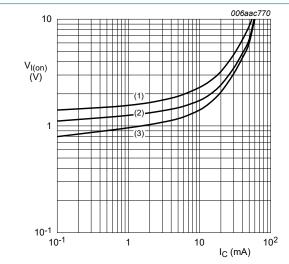


$$I_{\rm C}/I_{\rm B}=20$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 4. TR1 (NPN): Collector-emitter saturation voltage as a function of collector current; typical values



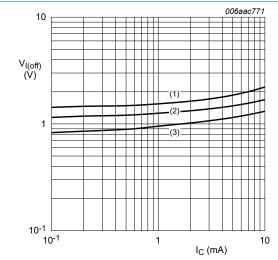
$$V_{CE}$$
 = 0.3  $V$ 

$$(1) T_{amb} = -40 °C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

$$(3) T_{amb} = 100 °C$$

Fig. 5. TR1 (NPN): On-state input voltage as a function | Fig. 6. of collector current; typical values



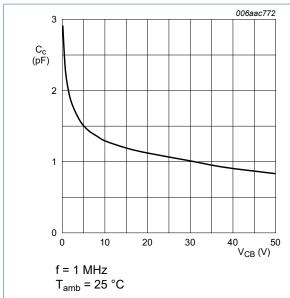
$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

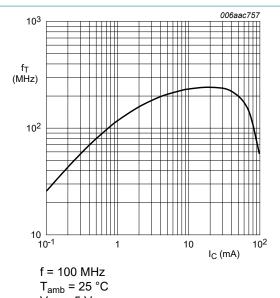
(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

TR1 (NPN): Off-state input voltage as a function of collector current; typical values

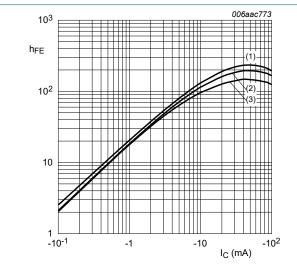


TR1 (NPN): Collector capacitance as a function Fig. 7. of collector-base voltage; typical values



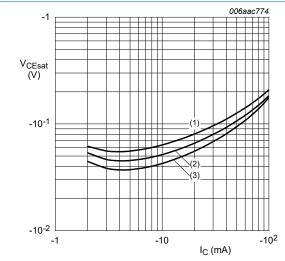
 $T_{amb}$  = 25 °C  $V_{CE}$  = 5 V

TR1 (NPN): Transition frequency as a function Fig. 8. of collector current; typical values of built-in transistor



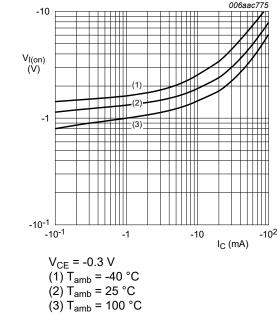
 $V_{CE}$  = -5 V(1) T<sub>amb</sub> = 100 °C (2) T<sub>amb</sub> = 25 °C (3)  $T_{amb} = -40 \, ^{\circ}C$ 

Fig. 9. TR2 (PNP): DC current gain as a function of collector current; typical values

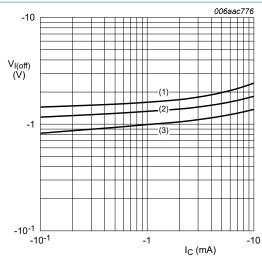


 $I_{\rm C}/I_{\rm B} = 20$ (1) T<sub>amb</sub> = 100 °C (2)  $T_{amb} = 25 \, ^{\circ}C$ (3)  $T_{amb} = -40 \, ^{\circ}C$ 

Fig. 10. TR2 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values



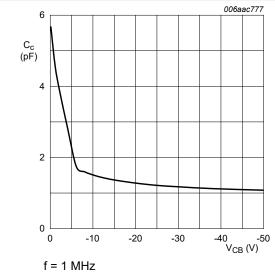
of collector current; typical values



V<sub>CE</sub> = -5 V (1) T<sub>amb</sub> = -40 °C (2) T<sub>amb</sub> = 25 °C

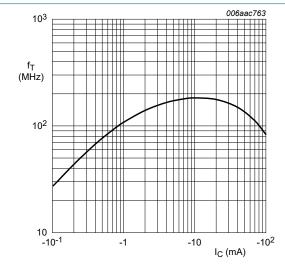
(3)  $T_{amb} = 100 \, ^{\circ}C$ 

Fig. 11. TR2 (PNP): On-state input voltage as a function | Fig. 12. TR2 (PNP): Off-state input voltage as a function of collector current; typical values



 $T_{amb} = 25 \, ^{\circ}C$ 

Fig. 13. TR2 (PNP): Collector capacitance as a function of collector-base voltage; typical values



f = 100 MHz

 $T_{amb}$  = 25 °C

 $V_{CE} = -5 V$ 

Fig. 14. TR2 (PNP): Transition frequency as a function of collector current; typical values of built-in transistor

## 11. Test information

#### **Resistor calculation**

• Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{1})}{I_{2} - I_{1}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I3)}{R1 \cdot I3} - 1$$

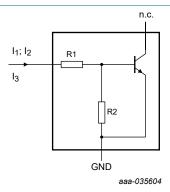


Fig. 15. TR1 (NPN): Resistor test circuit

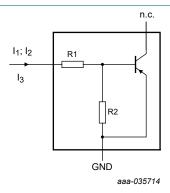


Fig. 16. TR2 (PNP): Resistor test circuit

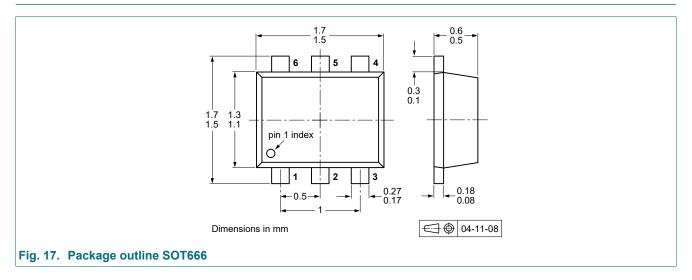
#### **Resistor test conditions**

Table 8. Resistor test conditions

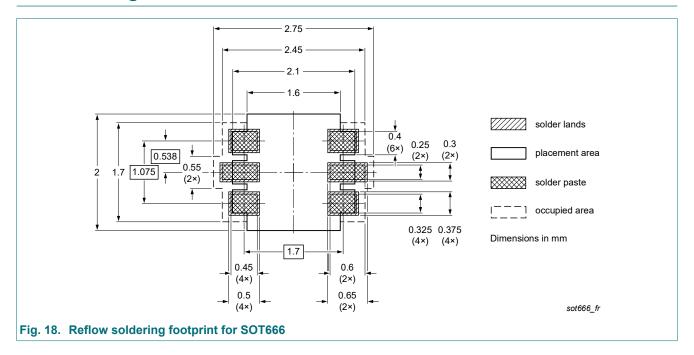
PEMD3	R1 (kΩ)	R2 (kΩ)	Test conditions				
			I <sub>1</sub>	l <sub>2</sub>	l <sub>3</sub>		
TR1 (NPN)	10	10	350 μΑ	450 μΑ	-400 μΑ		
TR2 (PNP)	10	10	-350 µA	-450 μA	400 μΑ		

50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$ 

# 12. Package outline



## 13. Soldering



50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$ 

# 14. Revision history

## Table 9. Revision history

lable 9. Revision history				
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PEMD3 v.12	20221228	Product data sheet	-	PEMD3_PIMD3_PUMD3 v.11
Modification:	_	sheet reduced to single type of hanged to non-automotive qu		
PEMD3_PIMD3_PUMD3 v.11	20130925	Product data sheet	-	PEMD3_PIMD3_PUMD3 v.10
PEMD3_PIMD3_PUMD3 v.10	20091115	Product data sheet	-	PEMD3_PIMD3_PUMD3 v.9
PEMD3_PIMD3_ PUMD3 v.9	20050518	Product data sheet	-	PEMD3_PIMD3_PUMD3 v.8
PEMD3_PIMD3_ PUMD3 v.8	20041206	Product data sheet	-	PEMD3_PUMD3 v.7

#### 50 V, 100 mA NPN/PNP resistor-equipped double transistor; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

## 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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Date of release: 28 December 2022

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